NSN 5962-01-476-6121

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-476-6121

| Maximum Power Dissipation Rating: |
|--|
| 330.0 milliwatts |
| Operating Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| Features Provided: |
| Monolithic |
| Inclosure Configuration: |
| Dual-in-line |
| Terminal Surface Treatment: |
| Solder |
| Product Name: |
| Microcircuits, memory, digital, cmos 512k x 8-bit uveprom, monolithic silicon |
| Voltage Rating And Type Per Characteristic: |
| -0.6 volts power source and 7.0 volts power source |
| Memory Device Type: |
| Eprom |
| Special Features: |
| Blank eprom to be programmed to p/n specified under master eprom; 5962-9175204mxa |
| Test Data Document: |
| $96906 \hbox{-mil-std-}883 \ standard \ (includes \ industry \ or \ association \ standards, \ individual \ manufactureer \ standards, \ etc.).$ |
| Terminal Type And Quantity: |
| 32 printed circuit |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| Yes - demil/mli |
| Fiig: |
| A458a0 |
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